

4/17/2013



**RELIABILITY MONITOR REPORT  
FOR**

**MFN SiGe HBT 0.5 $\mu$ m CMOS (GST40)**

**MAXIM INTEGRATED**

**160 RIO ROBLES  
SAN JOSE, CA 95134**

**This Report was prepared by  
MAXIM INTEGRATED Reliability Engineering**

**Summary:**

The data in the tables that follow was generated as the result of an on-going Process Reliability Monitor. The specific products in this process monitor are:

MAX2021ETX+	MAX2058ETL+	MAX2140ETH+	MAX3815CCM+
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The calculated failure rate for devices using this process is:

**FAILURE RATE: MTTF (YRS): 24854 QUANTITY: 303 FAILS: 0 FITS: 4.6**

The parameters used to calculate this failure rate are as follows:

**Cf: 60% Ea: 0.7 Tu: 25 °C**

The reliability data follows and in this section is the detailed reliability data by stress. The reliability data section includes the latest data available. This report covers data between 4/1/2012 and 3/31/2013 .

**Process Information:**

Process Description: MFN SiGe HBT 0.5µm CMOS (GST40)

**OPERATING LIFE**

DESCRIPTION	DATE CODE	TEST VEHICLE	CONDITION	READPOINT	QUANTITY	FAILS	LOT NO.
HIGH TEMP OP LIFE	1153	MAX2140ETH+	135°C	524 HRS	79	0	NEZ0E2865E
HIGH TEMP OP LIFE	1153	MAX2140ETH+	135°C	500 HRS	80	0	NEZ0E2864E
HIGH TEMP OP LIFE	1206	MAX2021ETX+	135°C	192 HRS	48	0	NZF0AA063CQ
HIGH TEMP OP LIFE	1206	MAX2021ETX+	135°C	192 HRS	32	0	NZF0AA063DQ
HIGH TEMP OP LIFE	1209	MAX2058ETL+	135°C	500 HRS	32	0	NT40A2220D
HIGH TEMP OP LIFE	1216	MAX3815CCM+	135°C	500 HRS	32	0	NXQ0A2194F
<b>Total:</b>						<b>0</b>	
<b>FAILURE RATE:</b>	<b>MTTF (YRS): 24854</b>		<b>QUANTITY: 303</b>		<b>FAILS: 0</b>		<b>FITS: 4.6</b>